NSN 5962-01-040-1434

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View Online at https://aerobasegroup.com/nsn/5962-01-040-1434
Body Length:
Between 0.750 inches and 0.785 inches
Body Width:
Between 0.220 inches and 0.291 inches
Body Height:
0.199 inches
Maximum Power Dissipation Rating:
512.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and negative outputs and w/enable and w/open collector and wire-or outputs and programmable and
programmed and w/buffered output and positive outputs and high speed and w/decoded output
Inclosure Material:
Ceramic or glass or metal
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
6 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
30003-247as-c0349 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:

Voc. domil/mli

Unit Of Measure:

Demilitarization:

N/a

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